- 1-A Output Current Capability Per Driver
- Pulsed Current 2-A Driver
- Wide Supply Voltage Range: 4.5 V to 36 V
- **Separate Input-Logic Supply**
- **NE Package Designed for Heat Sinking**
- Thermal Shutdown
- Internal ESD Protection
- High-Noise-Immunity Inputs
- Functional Replacement for SGS L293

description

The L293 is a quadruple high-current half-H driver designed to provide bidirectional drive currents of up to 1 A at voltages from 4.5 V to 36 V. It is designed to drive inductive loads such as relays, solenoids, dc and bipolar stepping motors, as well as other high-current/high-voltage loads in positive-supply applications.

All inputs are TTL compatible. Each output is a complete totem-pole drive circuit with a Darlington transistor sink and a pseudo-Darlington source. Drivers are enabled in pairs with drivers 1 and 2 enabled by 1,2EN and drivers 3 and 4 enabled by 3,4EN. When an enable input is high, the associated drivers are enabled and their outputs are active and in phase with their inputs. When the enable input is low, those drivers are disabled and their outputs are off and in a high-impedance state. With the proper data inputs, each pair of drivers form a full-H (or bridge) reversible drive suitable for solenoid or motor applications.

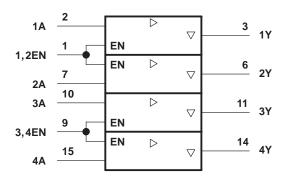
External high-speed output clamp diodes should be used for inductive transient suppression. A V_{CC1} terminal, separate from V_{CC2}, is provided for the logic inputs to minimize device power dissipation.

The L293 is designed for operation from 0°C to 70°C.

NE PACKAGE (TOP VIEW) 1,2EN 16 V_{CC1} 1A [2 15 AA 1Υ **Π** 3 14 1 4Y 13 П **HEAT SINK AND** 4 ∫ GROUND **GROUND** 5 12 11 3Y 2Y 🛮 6 10 3A 2А П 7 8 9 3,4EN

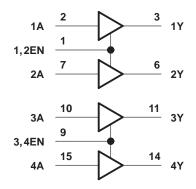
 V_{CC2} \sqcup

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC publication 617-12.

logic diagram



FUNCTION TABLE (each driver)

INP	OUTPUT	
Α	EN	Y
Н	Н	Н
L	Н	L
X	L	Z

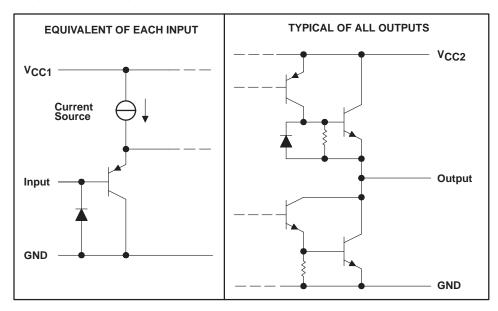
H = high-level, L = low-level,

X = irrelevant, Z = high-impedance (off)

[‡]In the thermal shutdown mode, the output is in the high-impedance state regardless of the input levels.



schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC1} (see Note 1)	36 V
Output supply voltage range, V _{CC2}	36 V
Input voltage range, V _I	7 V
Output voltage range, V _O	$-3 \text{ V to V}_{CC2} + 3 \text{ V}$
Peak output current, I _O (nonrepetitive, t ≤ 5 ms)	±2 A
Continuous output current, IO	±1 A
Continuous total dissipation at (or below) 25°C free-air temperature (see Notes 2 and 3)) 2075 mW
Continuous total dissipation at 80°C case temperature (see Note 3)	5000 mW
Operating case or virtual junction temperature range, T _A	40°C to 150°C
Storage temperature range, T _{stq}	−65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

- NOTES: 1. All voltage values are with respect to the network ground terminal.
 - 2. For operation above 25°C free-air temperature, derate linearly at the rate of 16.6 mW/°C.
 - $3. \quad \text{For operation above } 25^{\circ}\text{C} \text{ case temperature, derate linearly at the rate of } 71.4\,\text{mW/}^{\circ}\text{C}. \text{ Due to variations in individual device electrical linearly } 1.0\,\text{cm}^{-1}\text{C} \text{ and } 1.0\,\text{cm}^{-1}\text{C$ characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

recommended operating conditions

		MIN	MAX	UNIT
Logic supply voltage, V _{CC1}		4.5	7	V
Output supply voltage, V _{CC2}			36	V
High-level input voltage, VIH	V _{CC1} ≤ 7 V	2.3		V
	V _{CC1} ≥ 7 V	2.3	7	
Low-level output voltage, V _{IL}		-0.3†	1.5	V
Operating free-air temperature, T _A		0	70	°C

[†] The algebraic convention, in which the least positive (most negative) designated minimum, is used in this data sheet for logic voltage levels.



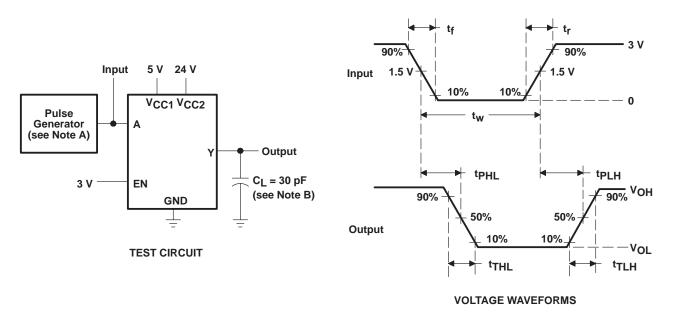
electrical characteristics, V_{CC1} = 5 V, V_{CC2} = 24 V, T_A = 25°C

PARAMETER TI		TEST CONDITIONS	MIN	TYP	MAX	UNIT			
Vон	High-level output voltage		I _{OH} = -1 A		V _{CC2} -1.8	V _{CC2} -1.4		V	
VOL	Low-level output voltage		I _{OL} = 1 /	I _{OL} = 1 A		1.2	1.8	V	
1	High lovel input ourrent	А	V. 7V			0.2	100		
I _{IH} High-level input current		EN	V _I = 7 V			0.2	±10	μΑ	
I	I _{IL} Low-level input current A EN		V _I = 0			-3	-10		
'IL						-2	-100	μΑ	
	-			All outputs at high level		13	22	mA	
ICC1 Logic supply current		$I_O = 0$	All outputs at low level		35	60			
				All outputs at high impedance		8	24		
	Output supply current		I _O = 0	All outputs at high level		14	24		
I _{CC2}				All outputs at low level		2	6	mA	
				All outputs at high impedance		2	4		

switching characteristics, V_{CC1} = 5 V, V_{CC2} = 24 V, T_A = 25°C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level output from A input			800		ns
tPHL	Propagation delay time, high-to-low-level output from A input	C _I = 30 pF, See Figure 1		400		ns
tTLH	Transition time, low-to-high-level output	CL = 30 pr, See rigule i		300		ns
tTHL	Transition time, high-to-low-level output			300		ns

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: $t_{\text{f}} \leq$ 10 ns, $t_{\text{f}} \leq$ 10 ns, t_{W} = 10 μ s, PRR = 5 kHz, Z_{O} = 50 Ω .

B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms



APPLICATION INFORMATION

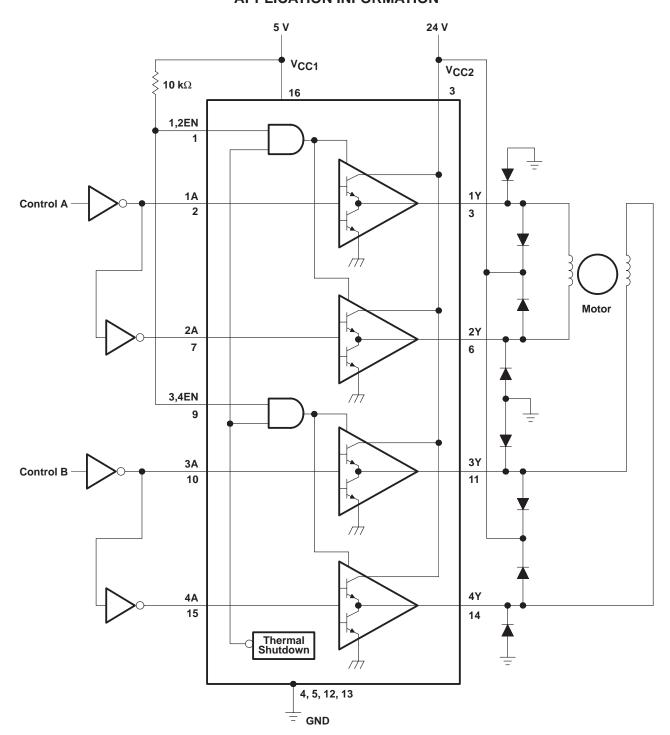


Figure 2. Two-Phase Motor Driver

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated